

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
60V	2Ω @ V _{GS} = 10V	320mA
60 V	3Ω @ V _{GS} = 5V	260mA

Description

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Motor Control
- **Power Management Functions**

Features

- Low On-Resistance: RDS(ON)
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- **ESD Protected Gate**
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

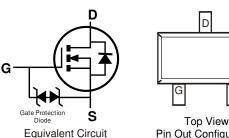
- Case: SOT-523
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 3
- Terminal Connections: See Diagram
- Weight: 0.002 grams (Approximate)





SOT-523

Top View



Pin Out Configuration

Ordering Information (Note 4)

Part Number	Case	Packaging
DMN63D1LT-7	SOT-523	3000/Tape & Reel
DMN63D1LT-13	SOT-523	10000/Tape & Reel

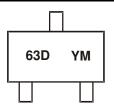
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. Notes:

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



Date Code Kev

Build bould filey												
Year	2014		2015	2016		2017	2018		2019	2020		2021
Code	В		С	D		E	F		G	Н		
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

⁶³D = Product Type Marking Code YM = Date Code Marking Y = Year (ex: C = 2015) M = Month (ex: 9 = September)



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		V _{DSS}	60	V	
Gate-Source Voltage	V _{GSS}	±20	V		
(Continuous Drain (Current (Note 6)) Voc = 10V		$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	320 260	mA
Maximum Continuous Body Diode Forward Currer	nt (Note 6)	Is	0.5	A	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1	%)	I _{DM}	1.2	A	

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	260	mW
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{0JA}	497	°C/W
Total Power Dissipation (Note 6)		PD	330	mW
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{0JA}	389	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

				-		
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV _{DSS}	60		_	V	$V_{GS} = 0V, I_D = 10\mu A$
Zero Gate Voltage Drain Current	I _{DSS}	_	—	1.0	μΑ	$V_{DS} = 60V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}			±10	μΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(TH)}	1.0	1.6	2.5	V	$V_{DS} = 10V, I_{D} = 1mA$
Static Drain-Source On-Resistance				2.0	Ω	$V_{GS} = 10V, I_D = 0.5A$
	R _{DS(ON)}		_	3.0	12	$V_{GS} = 5V, I_D = 0.05A$
Forward Transfer Admittance	Y _{fs}	80		_	mS	$V_{DS} = 10V, I_D = 0.2A$
Diode Forward Voltage	V _{SD}		0.75	1.2	V	$V_{GS} = 0V, I_{S} = 115mA$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		30	_	pF	
Output Capacitance	Coss		4.2	_	рF	V _{DS} = 25V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss		2.9	_	рF	1 = 1.00012
Gate Resistance	Rg		133	_	Ω	$f = 1MHz$, $V_{GS} = 0V$, $V_{DS} = 0V$
Total Gate Charge	Qg		392	_	рС	
Gate-Source Charge	Qgs		157	—	рС	V _{GS} = 4.5V, V _{DS} = 10V, I _D = 250mA
Gate-Drain Charge	Q _{gd}		92	_	рС	ID = 23011A
Turn-On Delay Time	t _{D(ON)}		3.9	_	ns	
Turn-On Rise Time	t _R		3.4	_	ns	$V_{DD} = 30V, V_{GS} = 10V,$
Turn-Off Delay Time	t _{D(OFF)}		15.7	_	ns	$R_G = 25\Omega$, $I_D = 200mA$
Turn-Off Fall Time	t _F		9.9	_	ns	

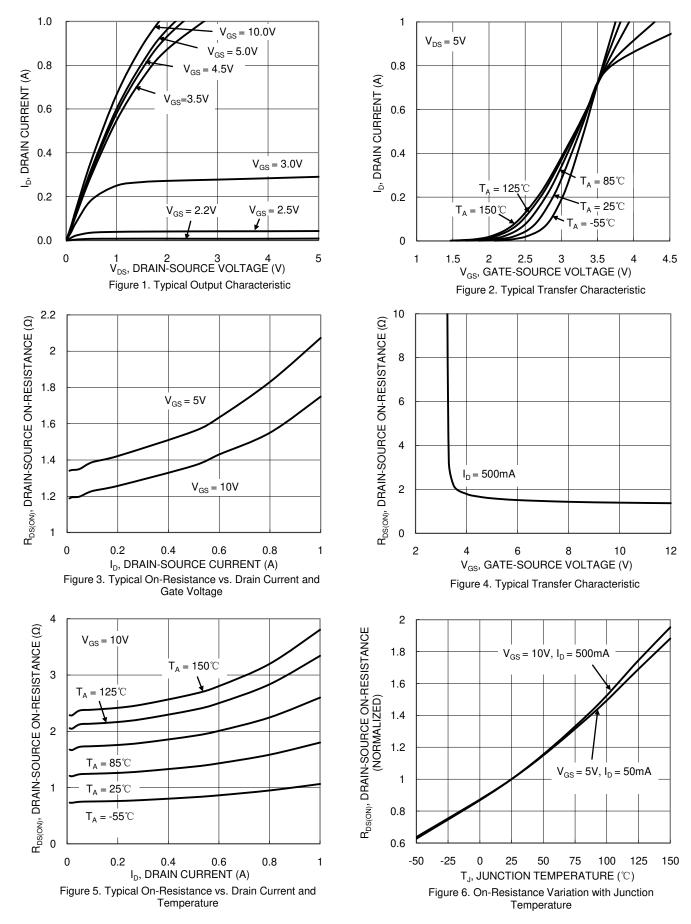
Notes:

5. Device mounted on FR-4 PCB, with minimum recommended pad layout.

Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.
Short duration pulse test used to minimize self-heating effect.

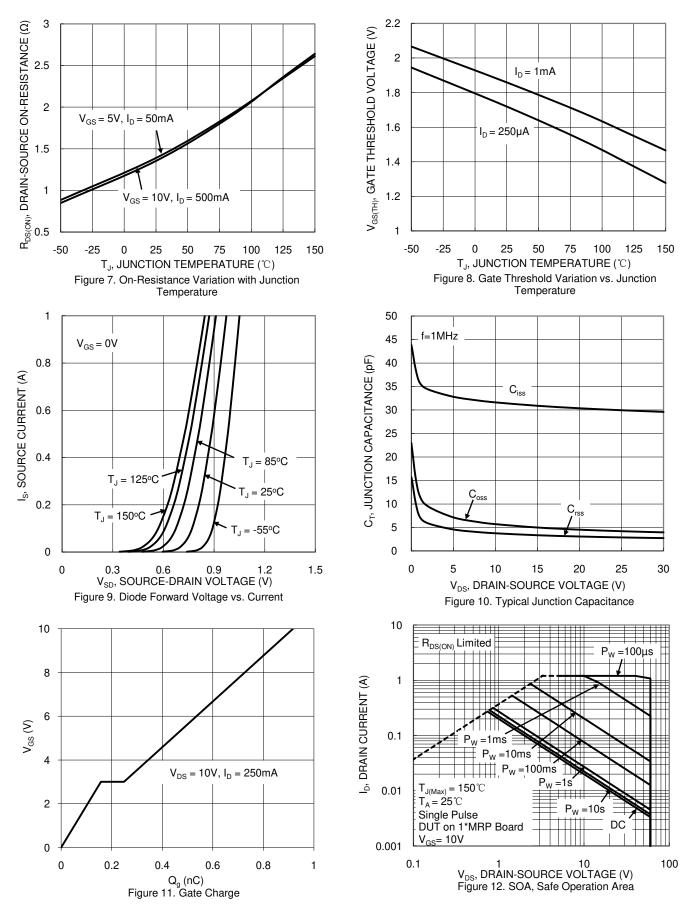
8. Guaranteed by design. Not subject to product testing.







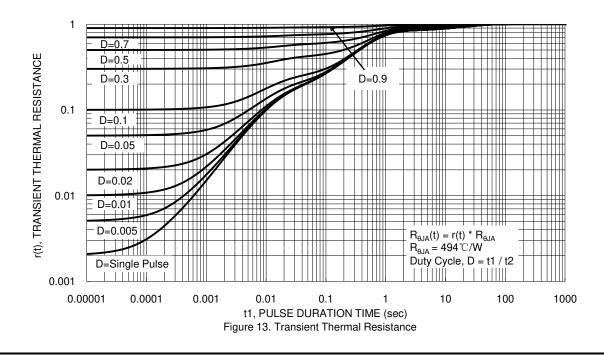
DMN63D1LT



NEW PRODUCT

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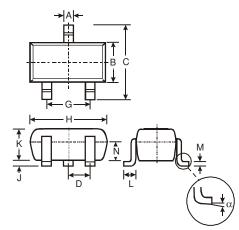




Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

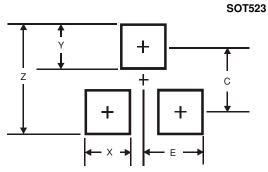
SOT523



SOT523							
Dim	Min	Max	Тур				
Α	0.15	0.30	0.22				
В	0.75	0.85	0.80				
С	1.45	1.75	1.60				
D	_		0.50				
G	0.90	1.10	1.00				
Н	1.50	1.70	1.60				
J	0.00	0.10	0.05				
K	0.60	0.80	0.75				
L	0.10	0.30	0.22				
М	0.10	0.20	0.12				
Ν	0.45	0.65	0.50				
α	0°	8°					
All Dimensions in mm							

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	1.8
Х	0.4
Y	0.51
C	1.3
E	0.7

DMN63D1LT Document number: DS37551 Rev. 2 - 2



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